

Low Power QUAD Operational Amplifiers

Product Description

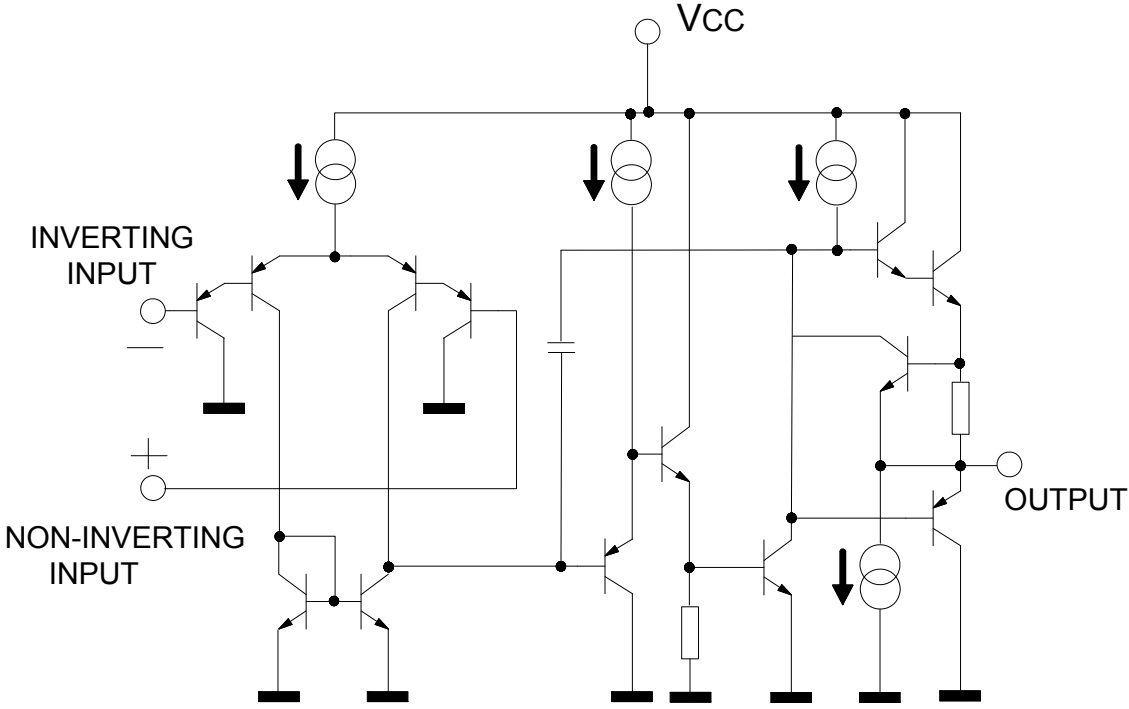
The GS324 consists of four independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the low power supply current drains in independent of the magnitude of the power supply voltage.

Application areas include transducer amplifiers, DC gain blocks and all the conventional op amp circuits, which now can be more easily implemented in single power supply systems. For example, the GS324 can be directly operated off of the standard +5V power supply voltage which is used in digital systems and will easily provide the required interface electronics without requiring the additional $\pm 15V$ power supplies.

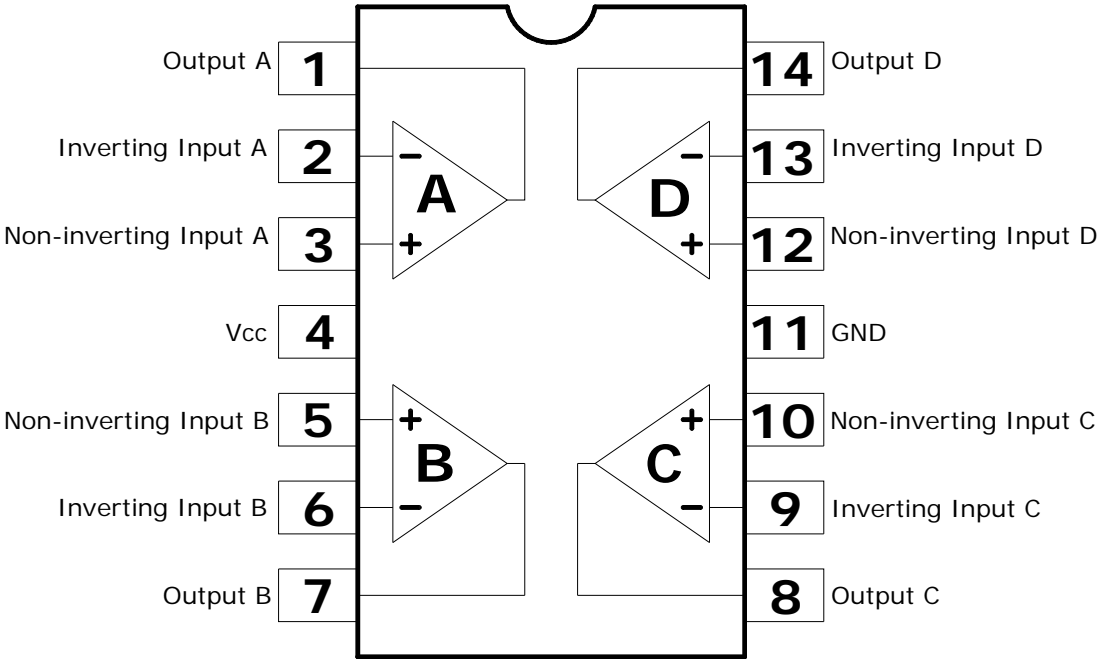
Features

- Wide range of supply voltages 3V to 30V
- Low supply current drain independent of supply voltage 1.5mA TYP.
- Low input biasing current
- Low input offset voltage and offset current
- Input common-mode voltage range includes ground
- Differential input voltage range equal to the power supply voltage
- DC voltage gain: 100V/mV TYP.
- Internally frequency compensation

Block Diagram



Pin Assignments

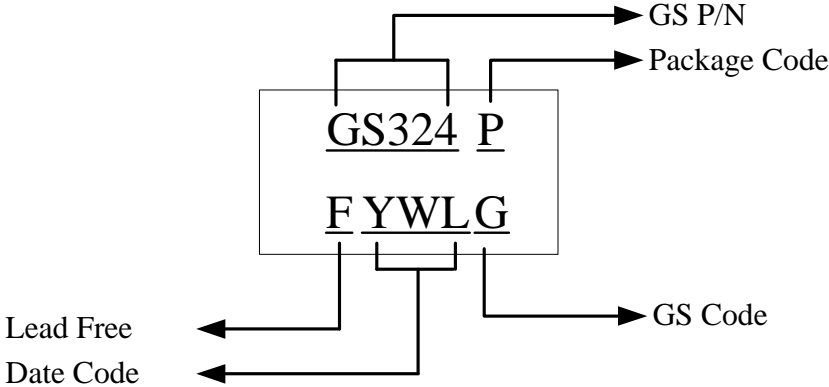


Ordering Information

GS Brand Name → GS
 Part Number → 324
 Package Code → PF
 Pb Free Code → (indicated by a blue underline in the original image)

Device	Package
GS324PF	DIP-14
GS324SF	SOP-14

Marking Information



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit	
Single supply	V_{CC}	32	V	
Split supply	V_{CC}, V_{EE}	± 16	V	
Input differential voltage range	V_{IDR}	± 32	V	
Output short-circuit to GND	I_{OS}	Continuous		
Junction temperature	T_J	150	$^{\circ}\text{C}$	
Storage temperature range	T_{STG}	-65 to +150	$^{\circ}\text{C}$	
Operating ambient temperature range	T_A	0 to 70	$^{\circ}\text{C}$	
Junction to ambient Thermo Resistance	θ_{JA}	DIP-14	115	$^{\circ}\text{C}/\text{W}$
		SOP-14	160	
Junction to Case Thermo Resistance	θ_{JC}	DIP-14	41	$^{\circ}\text{C}/\text{W}$
		SOP-14	23	
ESD Rating (HBM)	ESD	2K	V	

Electrical Characteristics

at specified free-air temperature, $V_{CC}=5\text{V}$ (Unless Otherwise Noted)

Parameter	Symbol	Test Conditions*	Min	Typ	Max	Unit	
Input offset voltage	V_{IO}	$V_{CC}=5\text{V to Max.}$ $V_{IC}=V_{ICR \text{ min}}, V_o=1.4\text{V}$	25 $^{\circ}\text{C}$		3	7	mV
			Full range			9	
Average temperature coefficient of input offset voltage	αV_{IO}		Full range		7		$\mu\text{V}/^{\circ}\text{C}$
Input offset current	I_{IO}	$V_o=1.4\text{V}$	25 $^{\circ}\text{C}$		2	50	nA
			Full range			150	
Average temperature coefficient of input offset current	αI_{IO}		Full range		10		$\text{pA}/^{\circ}\text{C}$
Input bias current	I_{IB}	$V_o=1.4\text{V}$	25 $^{\circ}\text{C}$		-20	-250	nA
			Full range			-500	
Common-mode input voltage range	V_{ICR}	$V_{CC} = 5\text{V to MAX}$	25 $^{\circ}\text{C}$	0 to $V_{CC}-1.5$			V
			Full range	0 to $V_{CC}-2$			
High-level output voltage	V_{OH}	$R_L \geq 2\text{k}\Omega$	25 $^{\circ}\text{C}$	$V_{CC} - 1.5$			V
		$V_{CC}=\text{MAX}, R_L=2\text{k}\Omega$	Full range	26			
		$V_{CC}=\text{MAX}, R_L \geq 10\text{k}\Omega$	Full range	27	28		
Low-level output voltage	V_{OL}	$R_L \geq 10\text{k}\Omega$	Full range		5	20	mV
Large-signal differential voltage amplification	A_{VD}	$V_{CC}=15\text{V}$ $V_o=1\text{V to }11\text{V}$ $R_L \geq 2\text{k}\Omega$	25 $^{\circ}\text{C}$	25	100		V/mV
			Full range	15			
Common-mode rejection ratio	CMRR	$V_{CC}=5\text{V to MAX}$ $V_{IC}=V_{ICR \text{ min}}$	25 $^{\circ}\text{C}$	65	80		dB
Supply voltage rejection ratio ($\Delta V_{CC}/\Delta V_{IO}$)	K_{SVR}	$V_{CC}=5\text{V to MAX}$	25 $^{\circ}\text{C}$	65	100		dB
Crosstalk attenuation	V_{O1}/V_{O2}	$f=1\text{kHz to }20\text{kHz}$	25 $^{\circ}\text{C}$		120		dB
Output current	I_o	$V_{CC}=15\text{V},$ $V_{ID}=1\text{V}, V_o=0\text{V}$	25 $^{\circ}\text{C}$	-20	-30		mA
			Full range	-10			
		$V_{CC}=15\text{V}$ $V_{ID}=-1\text{V}, V_o=15\text{V}$	25 $^{\circ}\text{C}$	10	20		
			Full range	5			
$V_{ID}=-1\text{V}, V_o=200\text{mV}$	25 $^{\circ}\text{C}$	12	30		μA		

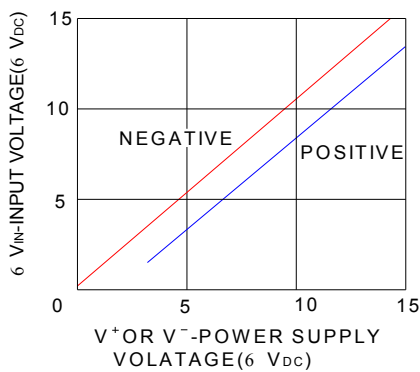
Electrical Characteristics (Continue)

Parameter	Symbol	Test Conditions*		Min	Typ	Max	Unit
Short-circuit output current	I_{OS}	V_{CC} at 5V, GND at -5V, $V_o=0V$	25°C		±40	±60	mA
Supply current (two amplifiers)	I_{CC}	$V_o=2.5V$, No load	Full range		1.5	2.4	mA
		$V_{CC}=\text{MAX}$, $V_o=0.5V_{CC}$, No load	Full range		1.1	3	

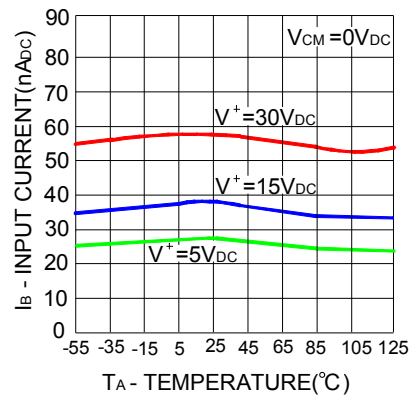
*All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. "MAX" V_{CC} for testing Purposes is 30V. Full range is 0°C to 70°C.

Typical Performance Characteristics

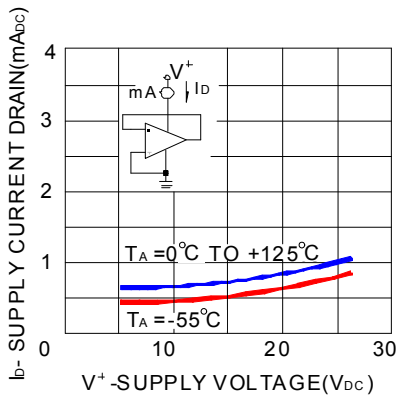
Input Voltage Range



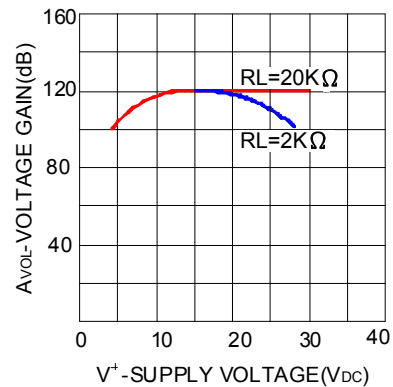
Input Current



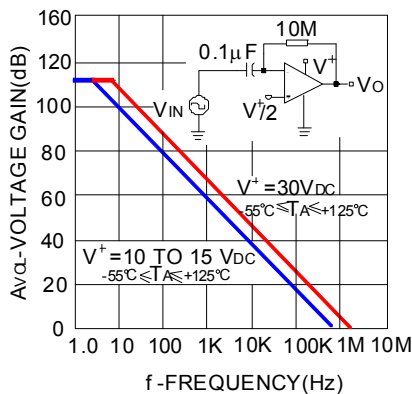
Supply Current



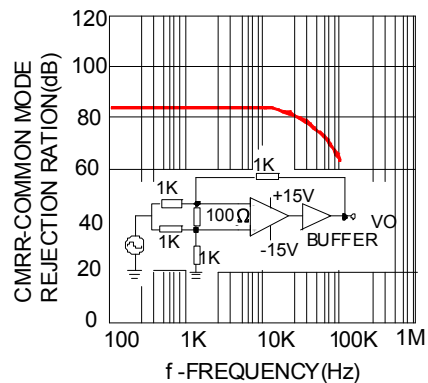
Voltage Gain



Open Loop Frequency Response

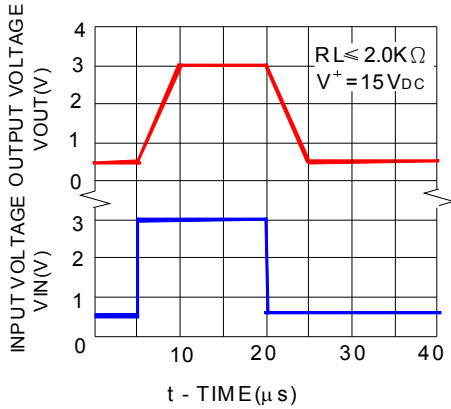


Common Mode Rejection Ratio

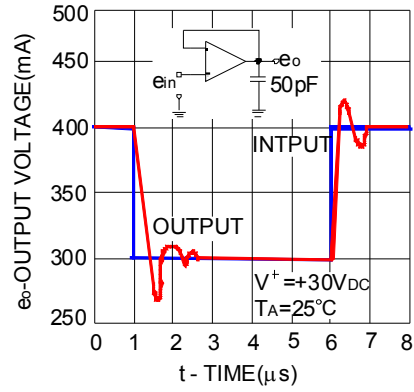


Typical Performance Characteristics (Continue)

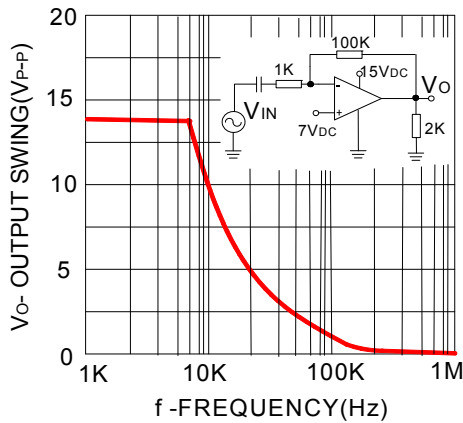
Voltage Follower Pulse Response



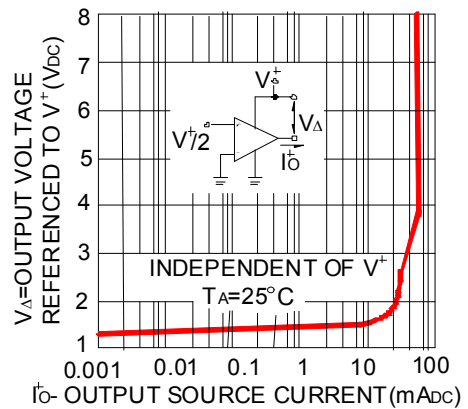
Voltage Follower Pulse Response (Small Signal)



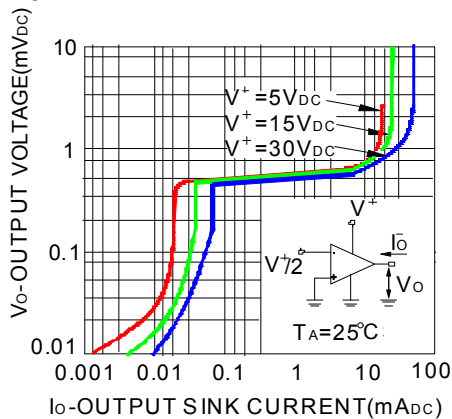
Large Signal Frequency Response



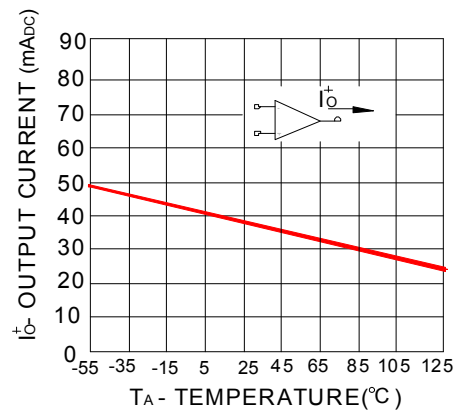
Output Characteristics current Sourcing



Output Characteristics Current Sinking

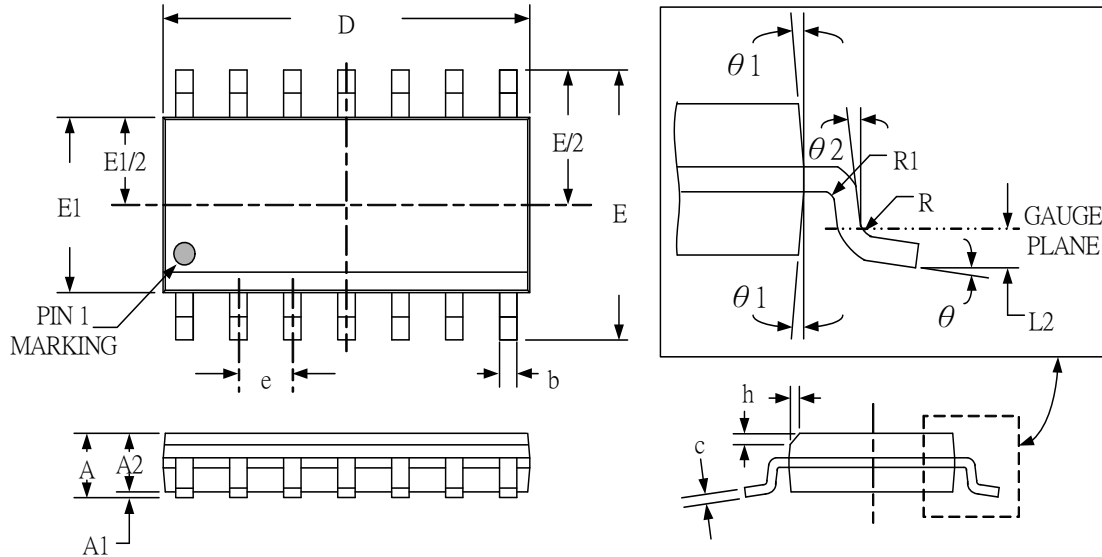


Current Limiting



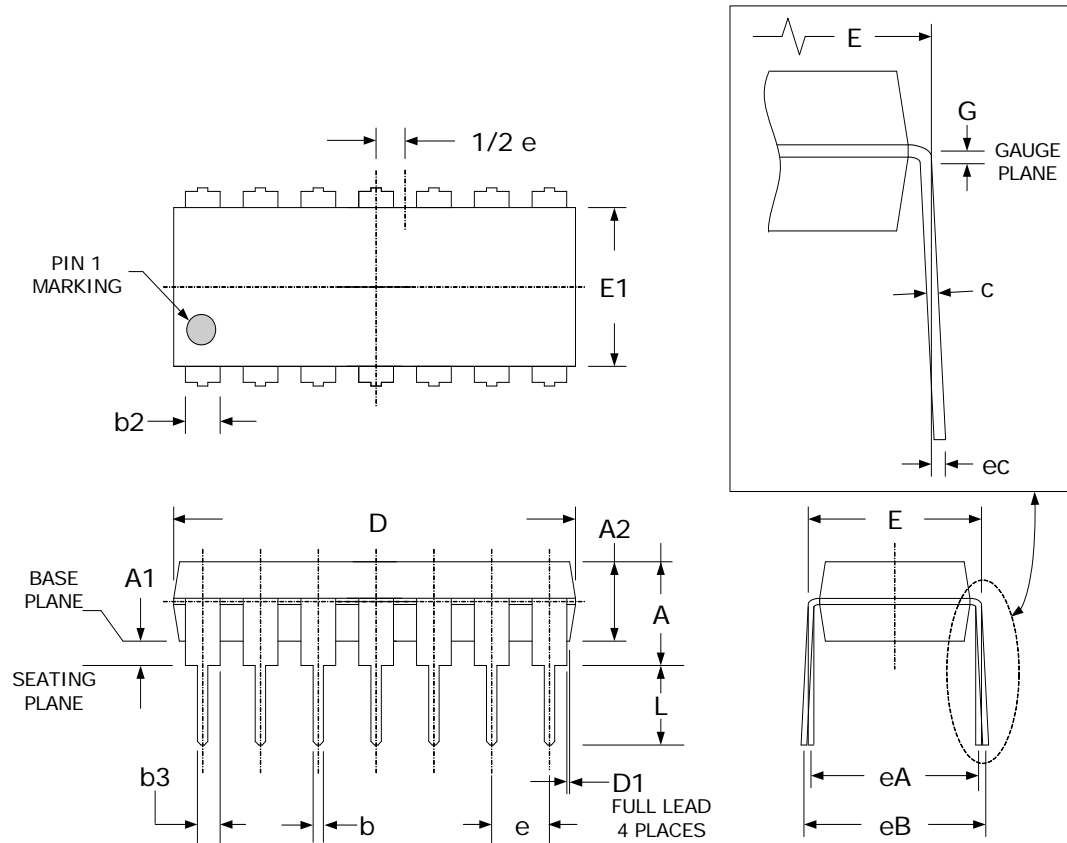
Package Dimension

SOP-14 PLASTIC PACKAGE



Dimensions				
SYMBOL	Millimeters		Inches	
	MIN	MAX	MIN	MAX
A	1.35	1.75	.053	.069
A1	0.10	0.25	.004	.010
A2	1.25	1.65	.049	.065
b	0.31	0.51	.012	.020
b1	0.28	0.48	.011	.019
c	0.17	0.25	.007	.010
D	8.65 (TYP)		.341 (TYP)	
E	6.00 (TYP)		.236 (TYP)	
E1	3.90 (TYP)		.154 (TYP)	
e	1.27 (TYP)		.050 (TYP)	
L	0.40	1.27	.016	.050
L1	1.04 (TYP)		.041 (TYP)	
L2	0.25 (TYP)		.010 (TYP)	
R	0.07	-	.003	-
R1	0.07	-	.003	-
h	0.25	0.50	.010	.020
θ	0°	8°	0°	8°
θ_1	5°	15°	5°	15°
θ_2	0°	-	0°	-

DIP-14 PLASTIC PACKAGE



Dimensions				
SYMBOL	Millimeters		Inches	
	MIN	MAX	MIN	MAX
A	-	5.33	-	.210
A1	0.38	-	.015	-
A2	2.92	4.95	.115	.195
b	0.36	0.56	.014	.022
b2	1.14	1.78	.045	.070
b3	0.76	1.14	.030	.045
c	0.20	0.36	.008	.014
D	18.67	19.69	.735	.775
D1	0.13	-	.005	-
E	7.62	8.26	.300	.325
E1	6.10	7.11	.240	.280
e	2.54 (TYP)		.100 (TYP)	
eA	7.62 (TYP)		.300 (TYP)	
eB	-	10.92	-	.430
eC	0.00	1.52	.000	.060
L	2.92	3.81	.115	.150
G	0.38 (TYP)		.015 (TYP)	

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